Form PTO-1449

INFORMATION DISCLOSURE CITATION P E IN AN APPLICATION

(Use several sheets if necessary)

Docket Number 356952000304

Application Number 09/928,194

Applicant

K. E. PETERSON et al.

Filing Date August 17, 2001

Group Art Unit To Be Assigned

Mailing Date

September 14, 2001

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8-28-62

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Application Number 09/928,194

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Form PTO-1449	Docket Number 356952000304	Application Number 09/928,194		
INFORMATION DISCLOSERE CITATION	Applicant			
IN AN APPLICATION	Kurt E. PETERSEN et al.			
(Use several sheets if necessary)	Filing Date August 11, 2001	Group Art Unit 2811		
	Mailing Date January 11, 2002			

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OTHER DOCUMENTS

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